PBLSERIES

PBL3726/12

MASK - PROGRAMMABLE SPEECH CIRCUITS

SPEECH CIRCUIT

- MINIMUM NUMBER OF INEXPENSIVE EX-TERNAL COMPONENTS, 5 CAPACITORS AND 10 RESISTORS
- MUTE FUNCTION FOR PARALLEL OPERA-TION WITH DTMF GENERATOR OR DECA-DING IMPULSING
- LOW VOLTAGE OPERATION, DOWN TO 3.3 V
- VERY SHORT START-UP TIME
- SEPARATE POWER SUPPLY POSSIBLE FOR OUTPUT AMPLIFIER

DESCRIPTON

PBL3726/12 is a standard version of the PBL3726 family of the mask-programmable, monolithic integrated speech circuits for use in electronic telephones. It is designed for use with a low impedance microphone. Sending and receiving gain is regulated with line length. Different ranges of amplifier regulation for various current feeds can be obtained. Typical current feeds as 48 V 2 x 250 Ω 2 x 400 Ω and 36 V 2 x 250 Ω can be handled.



Application-dependent parameters such as line balance, sidetone level and frequency response are set by external components. Parameters are set independently which means easy adaptation for various market needs. An extra 20 dB amplifier can be used for various purposes such as extra receiving gain with volume control or active sidetone balance.



TEST CIRCUIT

ABSOLUTE MAXIMUM RATINGS

(Maximum Ratings over Operating Free-air Temperature Range unless otherwise stated)

Symbol	Parameter	ter Test Conditions	
VDC	Line Voltage, $t_p = 2 s$	22	V
I _{DC} (*)	Continuous Operating Line Current	100	mA
Tj	Junction Temperature	150	°C
Tamb	Operating Ambient Temperature	- 40 to + 70	°C
T _{stg}	Storage Temperature	- 55 to + 150	°C

(*) Max. current increases linearly up to 130 mA with max operating temperature lowered to + 55 °C.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Тур.	Max.	Unit
١	Line Current	15		100	mA

CONNECTION DIAGRAM



TEST SET-UP





THERMAL DATA

Rth i amb Thermal Resistance Junction-ambient Max 80 °C/					T
	Rth i-amb	Thermal Resistance Junction-ambient	Max	80	°C/W

ELECTRICAL CHARACTERISTICS (electrical characteristics over recommended operating conditions)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
VD	Terminal Voltage	I _{DC} = 15 mA I _{DC} = 100 mA	3.3 11	3.7 13	4.1 15	V V
GT	Transmitting Gain *	20. log10 ($\frac{V_2}{V3}$) 1 KHz R _L = 0 E = E + 10 % R _L = 900 Ω - 2.2 KHz	38 43	40 45	42 47	dB dB
REGT	Transmitting Range of Regulation		3	5	7	dB
Lin _T	Transmitting Frequency Response	200 Hz to 3.4 KHz	- 1	-	1	dB
G _R	Receiving Gain *	20 . log10 ($\frac{V_4}{V1}$) 1 KHz R _L = 0 Ω E = E + 10 % R _L = 900 Ω - 2.2 KΩ	- 18.5 - 13.5	- 16.5 - 11.5	- 14.5 - 9.5	dB dB
REG _R	Receiving Range of Regulation	$ \begin{array}{l} 1 \mbox{ KHz} \\ R_L = 0 \ \Omega \\ \mbox{to } R_L = 900 \ \Omega \end{array} \ E = E + 10 \ \% \label{eq:eq:expansion} $	3	5	7	dB
Lin _R	Receiving Frequency Response	200 Hz to 3.4 KHz	- 1		1	dB
ZIN	Transmitter Input Impedance	1 KHz		2.5		KΩ
VT	Transmitter Dynamic Output	200 Hz – 3.4 KHz ≤ 2 % Distortion I _{DC} = 20 – 100 mA		1.4		Vp
VŢ	Transmitter Max Output	200 Hz - 3.4 KHz I _{DC} = 0 - 100 mA V ₃ = 0 - 1 V		3		Vp
ZOUT	Receiver Output Impedance	1 KHz		3 + 310		Ω
VR	Receiver Dynamic Output **	200 Hz - 3.4 KHz ≤ 2 % Distortion I _{DC} = 20 - 100 mA		0.4		Vp
VR	Receiver Max Output	Measured with Line Rectifier 200 Hz - 3.4 KHz $I_{DC} = 0 - 100 \text{ mA}$ $V_1 = 0 - 50 \text{ V}$		0.9		Vp
NT	Transmitter Output Noise	P_{sof} -weighted, REL 1 V R _L = 0		- 75		dB _{psof}
N _R	Receiver Output Noise	A-weighted, REL 1 V, with Cable 0-5 Km Ø 0.5 mm ; 0-3 Km Ø 0.4 mm		- 85		dBA
IM	Mute Input Current		0.1			mA
IDC	Extra Available Current when Muted at the Same DC-voltage	I _{DC} = 15 - 100 mA		10		mA

* Adjustable to both higher and lower values with external components.

Figure 1 : Typical Application.



Some typical values for R1 and R2 for some different supplies from telephone stations are shown in the next table.

Туре	R1	R2
No Regulation, all Feeding Systems	00	0
48 V, 2 x 400 Ω	14.5 kΩ	47 kΩ
48 V, 2 x 200 Ω	18 kΩ	47 kΩ

